SURFACE MOUNT CHIP LED LAMP SPECIFICATION

PAGE:

REVISION:

2

1.0

● COMMODITY: SURFACE MOUNT CHIP LED LAMP

●DEVICE NUMBER: BL-HE1Y033

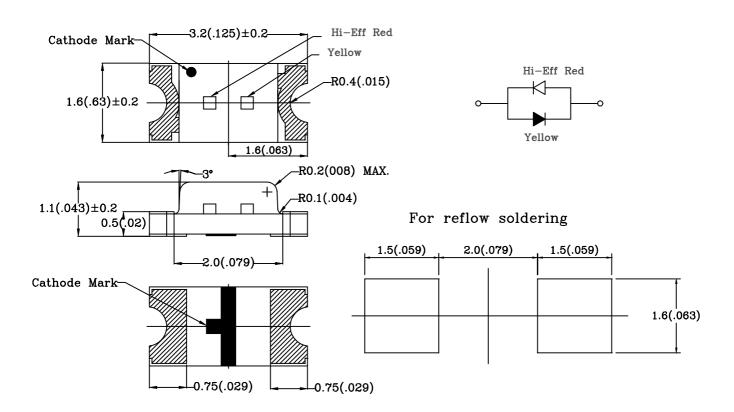
●ELECTRICAL AND OPTICAL CHARACTERISTICS (Ta=25°C)

Chip				Absolute Maximum				Electro-optical				T
Emitted Color	Peak Wave Length λ p(nm)	e Wave th Length	Lens Appearance	Rating			Data (At 20mA)			Viewing Angle		
				$\Delta \lambda$ (nm)	Pd (mW)	If (mA)	Peak If(mA)	Vf(V)		Iv Typ. (mcd)		$\begin{array}{c c} 2\theta & 1/2 \\ \text{(deg)} \end{array}$
								Тур.	Max.	Min	Тур.	(405)
Hi-Eff Red	640	628±5	Water Clear	40	80	30	100	2.0	2.6	5.5	12.0	120
Yellow	583	585±5		32	80	30	100	2.1	2.6	2.4	10.0	120

Remark: Viewing angle is the Off-axis angle at which the luminous intensity is half the axial luminous intensity.

lacktriangle ABSOLUTE MAXIMUM RATINGS (Ta=25 $^{\circ}$ C)

●PACKAGE DIMENSIONS



NOTES: 1.All dimensions are in millimeters (inches).

- 2. Tolerance is \pm 0.10mm (0.004) unless otherwise specified.
- 3. Specifications are subject to change without notice.
- 4. Condition for IFp is pulse of 1/10 duty and 0.1 msec width.

SURFACE MOUNT CHIP LED LAMP SPECIFICATION

● COMMODITY: SURFACE MOUNT CHIP LED LAMP

DEVICE NUMBER: BL-HE1Y033 PAGE: 3

ELECTRICAL AND OPTICAL CHARACTERISTICS (Ta=25°C)

Fig.1 RELATIVE INTENSITY VS. WAVELENGTH (Y) (E) 1.0 RELATIVE RADIANT INTENSITY 0.5 520 670 WAVELENGTH λ (nm)

Fig.2 FORWARD CURRENT DERATING CURVE

REVISION:

1.0

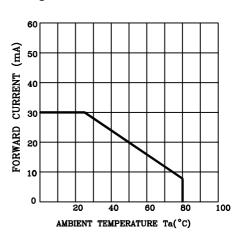


Fig.3 FORWARD CURRENT FORWARD VOLTAGE

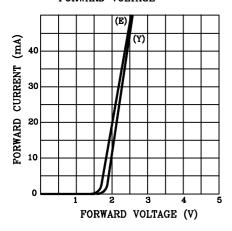
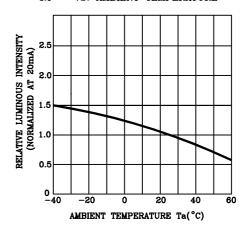


Fig.4 RELATIVE LUMINOUS INTENSITY VS. AMBIENT TEMPERATURE



VS. FORWARD CURRENT

Fig.5 RELATIVE LUMINOUS INTENSITY

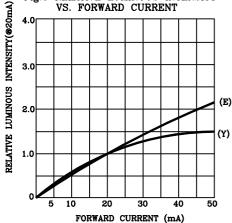
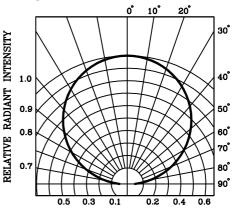


Fig.6 RADIATION DIAGRAM



SURFACE MOUNT CHIP LED LAMP SPECIFICATION

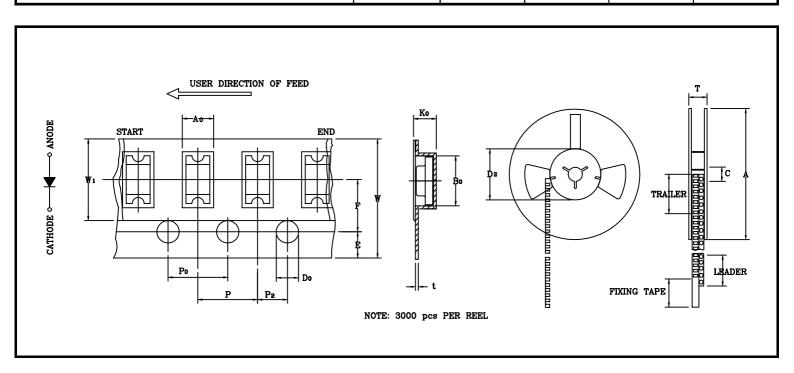
● COMMODITY: SURFACE MOUNT CHIP LED LAMP

●DEVICE NUMBER: BL-HE1Y033-TR

●ELECTRICAL AND OPTICAL CHARACTERISTICS (Ta=25°C) REVISION: 1.0

PAGE:

	SYMBOL	SPECIFICATION					
ITEM		Mini	mum	Maximum			
		mm	inch	mm	inch		
Tape Feed Hole Diameter (DIA)	D_0	1.40	0.055	1.60	0.063		
Feed Hole Location	Е	1.65	0.064	1.85	0.073		
Centers Line Dimensions Length Direction	F	3.45	0.135	3.55	0.139		
Compartment Depth	K_0	1.17	0.046	1.37	0.054		
Compartment Pitch	P	3.90	0.153	4.10	0.161		
Sprocket Hole Diameter	P_0	3.90	0.153	4.10	0.161		
Centers Line Dimensions Length Direction	P ₂	1.95	0.076	2.05	0.080		
Carrier Tape Thickness	t	_	_	0.30	0.012		
Carrier Tape Width	W	7.70	0.303	8.30	0.326		
Flange Diameter	A	178.0	7.008	180.0	7.087		
Hub Spindle Hole	С	12.50	0.492	13.50	0.531		
Hub Diameter	D_2	70.00	2.755	72.00	2.830		
Fixing Tape Width	W_1	5.25	0.206	5.35	0.210		
Flange Space Between Flanges	T	12.50	0.492	13.50	0.531		
Compartment Length	A_0	1.68	0.066	1.88	0.074		
Compartment Width	B_0	3.30	0.130	3.50	0.138		



SURFACE MOUNT CHIP LED LAMP SPECIFICATION

RELIABILITY TEST

REVISION: 1.0

PAGE:

5

Classification	Test Item	Reference Standard	Test Conditions	Result
Endurance Test	Operation Life	MIL-STD-750:1026 MIL-STD-883:1005 JIS C 7021 :B-1	Connect with a power If=20mA Ta=Under room temperature Test time=1,000hrs	0/20
	High Temperature High Humidity Storage	MIL-STD-202:103B JIS C 7021 :B-11	Ta= $+65^{\circ}$ C $\pm 5^{\circ}$ C RH=90%-95% Test time=240hrs	0/20
	High Temperature Storage	MIL-STD-883:1008 JIS C 7021 :B-10	High Ta=+85°C±5°C Test time=1,000hrs	0/20
	Low Temperature Storage	JIS-C-7021 :B-12	Low Ta=-35°C±5°C Test time=1,000hrs	0/20
Environmental Test	Temperature Cycling	MIL-STD-202:107D MIL-STD-750:1051 MIL-STD-883:1010 JIS C 7021 :A-4	-35°C ~ +25°C ~ +85°C ~ +25°C 60min 20min 60min 20min Test Time=5cycle	0/20
	Thermal Shock	MIL-STD-202:107D MIL-STD-750:1051 MIL-STD-883:1011	-35°C±5°C ~+85°C±5°C 20min 20min Test Time=10cycle	0/20
	Solder Resistance	MIL-STD-202:201A MIL-STD-750:2031 JIS C 7021 :A-1	Preheating: 140°C-160°C, within 2 minutes. Operation heating: 235°C (Max.), within 10seconds. (Max.)	0/20

JUDGMENT CRITERIA OF FAILURE FOR THE RELIABILITY

Measuring items	Symbol	Measuring conditions	Judgement criteria for failure
Forward voltage	$V_{F}(V)$	If=20mA	Over Ux1.2
Reverse current	Ir(uA)	Vr=5V	Over Ux2
Luminous intensity	Iv (mcd)	If=20mA	Below SX0.5

Note: 1.U means the upper limit of specified characteristics. S means initial value.

2.Measurment shall be taken between 2 hours and after the test pieces have been returned to normal ambient conditions after completion of each test.

SURFACE MOUNT CHIP LED LAMP SPECIFICATION

PAGE: 6 **REVISION:** 1.0

1. **SOLDERING:**

Manual Of Soldering

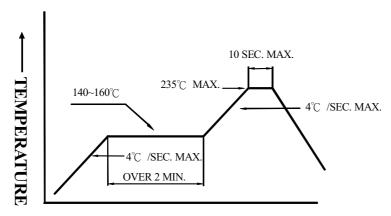
The temperature of the iron tip should not be higher than 300°C (572°F) and Soldering within 3 seconds per solder-land is to be observed.

Reflow Soldering

Preheating: 140° C ~ 160° C ±5°C, within 2 minutes.

Operation heating: 235°C (MAX.) within 10 seconds.(Max)

Gradual Cooling (Avoid quenching).

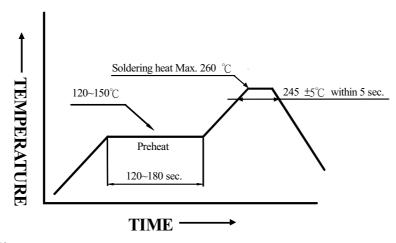


TIME -

DIP soldering (Wave Soldering)

Preheating: 120°C~150°C, within 120~180 sec. Operation heating: 245°C±5°C within 5 sec.260°C (Max)

Gradual Cooling (Avoid quenching).



2. **Handling:**

Care must be taken not to cause to the epoxy resin portion of BRIGHT LEDs while it is exposed to high temperature.

Care must be taken not rub the epoxy resin portion of BRIGHT LEDs with hard or sharp article such as the sand blast and the metal hook.

SURFACE MOUNT CHIP LED LAMP SPECIFICATION

PAGE: 7

REVISION: 1.0

3. Notes for designing:

Care must be taken to provide the current limiting resistor in the circuit so as to drive the BRIGHT LEDs within the rated figures. Also, caution should be taken not to overload BRIGHT LEDs with instantaneous voltage at the turning ON and OFF of the circuit.

When using the pulse drive care must be taken to keep the average current within the rated figures. Also, the circuit should be designed so as be subjected to reverse voltage when turning off the BRIGHT LEDs.

4. Storage:

In order to avoid the absorption of moisture, it is recommended to solder BRIGHT LEDs as soon as possible after unpacking the sealed envelope.

If the envelope is still packed, to store it in the environment as following:

- (1) Temperature: 5° C- 30° C(41° F)Humidity: RH 60% Max.
- (2) After this bag is opened, devices that will be applied to infrared reflow, vapor-phase reflow, or equivalent soldering process must be:
- a. Completed within 24 hours.
- b. Stored at less than 30% RH.
- (3) Devices require baking before mounting, if:
 - (2) a or (2) b is not met.
- (4) If baking is required, devices must be baked under below conditions:
 - 12 hours at $60\% \pm 3\%$.

5. Package and Label of Products:

- (1) Package: Products are packed in one bag of 3000 pcs (one taping reel) and a label is attached on each bag.
- (2) Label:

